### **Curriculum Vitae**

# Prof. Dr. Sefer Bora Lisesivdin, BSc (Engineering), MSc, PhD, SMIEEE

#### **CONTACT INFORMATION**

(1) Department of Physics

Gazi University, Ankara, Turkey 06500

Phone: +90 312 202 1391

Email: bora@gazi.edu.tr, sblisesivdin@gmail.com

Personal web: <a href="http://sblisesivdin.github.io">http://sblisesivdin.github.io</a>
Group web: <a href="http://www.lrgresearch.org">http://www.lrgresearch.org</a>

#### **EDUCATION**

2008	Ph.D. Physics, Gazi University, Ankara, Turkey	
	Dissertation: Electron and Magneto Transport Properties of AlGaN/GaN	
	Based High Electron Mobility Transistors (HEMTs)	
	Advisor: Prof. Dr. Mehmet Kasap	
2005	M.Sc. Advanced Technologies, Gazi University, Ankara, Turkey	
	Thesis: Transport Properties of InGaAs/GaAs and AlGaAs/GaAs	
	Semiconductors Grown by MBE	
	Advisor: Assoc. Prof. Dr. Mehmet Kasap	
2002	B.Sc (Eng). Physics Engineering, Hacettepe University, Ankara Turkey	
	Senior Project: Development of X-Ray Data Analysis Software for Windows	
	Systems	

### **RESEARCH INTERESTS**

Experimental and numerical investigation of electron and magnetotransport properties, strain, persistent photoconductivity, hot-electron transport properties, Shubnikov de Hass parameters and quantum parameters of 2 dimensional gas (2DEG) of III-V group semiconductor materials including, GaAs, GaN, InGaN, TiO<sub>2</sub> bulks and AlGaN/GaN, AlGaN/(AlN)/GaN, AlGaN/(AlN)/GaN/AlN, AlInN/AlN/GaN/AlN and AlInN/AlN/InGaN/AlN heterostructures, MgZnO/ZnO, BeZnO/ZnO heterostructures and graphene.

Numerical investigation of transport properties of low-dimensional systems as Quantum dots (0D), Quantum wires (1D), Quantum wells (2D),

### SCHOLARSHIPS / FELLOWSHIPS / AWARDS

2019	Leaders in Innovation Fellowship, Royal Academy of Engineering,
	United Kingdom,
2017	Duty Award, Gazi University Faculty of Science, Ankara, Turkey.
2016	Turkish Academy of Sciences, Distinguished Young Scientist Award
2015	IEEE Senior Membership
2015	SCI-indexed Publication Award, Gazi University, Ankara, Turkey.
2015	Duty Award, Gazi University Faculty of Science, Ankara, Turkey.
2014	Turkish Physical Union Prof. Dr. Sevket Erk Outstanding Young
	Scientist Award.
2014	SCI-indexed Publication Award, Gazi University, Ankara, Turkey.

2014	SCI-indexed Citation Award, Gazi University, Ankara, Turkey.
2013	TUBITAK 2219 scholarship for postdoc research (6 months).
2007-present	20 publications are promoted through TUBITAK Incentive Program for
	International Scientific Publications.
2010, 2012	SCI-indexed Publication Award, Gazi University, Ankara, Turkey.
2008-2009	Postdoc fellowship for postdoc studies.
2007-2008	TUBITAK 2214 scholarship for PhD research (6 months).
2007	Progetto Lagrange PhD Scholarship, Politechnico di Torino, Italy (not used
	due to family issues).
2005-2008	Several project scholarship for M.Sc. and Ph.D. studies.

# **GRANTS & PROJECT MEMBERSHIPS**

Earned grants as a project investigator (PI) or project co-investigator (co-PI)

2018-2019	TUBITAK 1512, 2180227, Production of Compact USB Fiber-coupled UV-
	VIS-NIR Optical Spectrometer for Industrial and Scientific Purposes, CEO
	and PI, Budget, 149 846 TL no-return grant (approximately 24 500 Euros)
2017-2020	TUBITAK 1001,116F197, Investigation of Growth Behaviors and 2DEG
	Properties of of MgZnO/ZnO Heterostructures grown by USPECVD
	Method, PI, Budget, 359 810 TL (approximately 88 600 Euros)
2014-2016	Joint grant of Scientific and Technological Research Council of Turkey and
	RFBR of Russia, 113F364, Manipulation properties of two-dimensional
	electronic gas using insitu surface passivation of AlGaN/GaN
	heterostructures by molecular beam epitaxy, PI, Budget: 282 910 TL
	(approximately 97 500 Euros)
2012-2013	University Research Grant, 05-2012/13, Numerical optimization of Mg <sub>x</sub> Zn <sub>1</sub> .
	<sub>x</sub> O/ZnO and Be <sub>x</sub> Zn <sub>1-x</sub> O/ZnO based heterostructure transistors, PI, Budget: 14
	889 TL (approximately 6 500 Euros)
2012-2013	University Research Grant, 05-2012/14, Investigation of the effects of
	transition metal palladium on electronical, structural and optical properties of
	graphene nanoribbons, PI, Budget: 14 955 TL (approximately 6 500 Euros)

# Project memberships

2010-2012	TUBITAK 1002 Support Project, 209T051, MOVPE growth and characterization of epitaxial germanium for infrared photovoltaic and sensor
	applications, Researcher, Budget: 25k TL (approximately 11k Euros)
2009-2012	TUBITAK 1007 Research Project, 107A012, Researcher, Budget: 4.7 M TL
	(approximately 2M Euros)
2008-2012	Military Related Research Project, SAVS020, Scholar, Budget: 5.8M TL
	(approximately 2 5M Euros)
2008-2010	TUBITAK 1001 Research Project, 108T018, Epitaxial growth and
	characterization of infrared AlGaAs laser diode materials, Scholar, Budget:
	358 400 TL (approximately 156k Euros)
2008-2010	TUBITAK (Turkey) - ANCS (Romania) Joint Research Project,
	TBAG-U/220 (107A584), Studies on synthesis and characterization of TiO2
	thinfilm nanostructures which have applications in ecological physics,
	Scholar, Budget: 58k TL (approximately 25k Euros)

2006-2009	Military Related Research Project, SAVM005, Researcher, Budget: 4.7 M
	TL (approximately 2M Euros)
2006-2007	TUBITAK 1007 Research Project, 105A005, Scholar, Budget: 5.5M TL
	(approximately 2 4M Euros)

# PROFESSIONAL APPOINTMENTS

Visiting Researcher, Institute for Quantum Optics, University of Ulm, Ulm,
Germany (3 months)
Full Professor, Department of Physics, Faculty of Science, Gazi University,
Ankara Turkey
Visiting Researcher, School of Computer Science and Electronics
Engineering, University of Essex, Colchester, UK.
Associate Professor, Department of Physics, Faculty of Science, Gazi
University, Ankara Turkey
Assistant Professor, Department of Physics, Faculty of Science and Arts,
Gazi University, Ankara Turkey
Post-doctoral Researcher, Nanotechnology Research Center, Bilkent
University, Ankara, Turkey <a href="http://www.nanotam.bilkent.edu.tr">http://www.nanotam.bilkent.edu.tr</a>

## RESEARCH EXPERIENCE

TESE TITE	AN ENGELVEE
2019-2020	Visiting Researcher, Institute for Quantum Optics, University of Ulm, Ulm,
	Germany (3 months)
2013	Visiting Researcher, Department of Computing and Electronic Systems
	University of Essex, Colchester, UK (6 months)
2008-2009	Post-doctoral Researcher, Nanotechnology Research Center, Bilkent
	University, Ankara, Turkey <a href="http://www.nanotam.bilkent.edu.tr">http://www.nanotam.bilkent.edu.tr</a>
2007-2008	Research Student, Department of Computing and Electronic Systems
	University of Essex, Colchester, UK (6 months)

## TEACHING EXPERIENCE

These courses correspond to a number of more than 2300 students as of this CV's writing time.

Institute of Science, Gazi University, Ankara, Turkey		
2019/2	Instructor, Fiz 522 Micro and Nanofabrication Methods	
2018/2	Instructor, Fiz 522 Micro and Nanofabrication Methods	
2018/1	Instructor, Fiz 522 Micro and Nanofabrication Methods	
2017/2	Instructor, Fiz 524 Physics of Low-dimensional Semiconductors	
2017/1	Instructor, Fiz 524 Physics of Low-dimensional Semiconductors	
2017/1	Instructor, Fiz 522 Micro and Nanofabrication Methods	
2016/2	Instructor, Fiz 524 Physics of Low-dimensional Semiconductors	
2016/2	Instructor, Fiz 522 Micro and Nanofabrication Methods	
2016/1	Instructor, Fiz 522 Micro and Nanofabrication Methods	
2015/2	Instructor, Fiz 522 Micro and Nanofabrication Methods	
2015/1	Instructor, Fiz 522 Micro and Nanofabrication Methods	
2014/2	Instructor, Fiz 522 Micro and Nanofabrication Methods	
2014/1	Instructor, Fiz 522 Micro and Nanofabrication Methods	

```
2013/2
                Instructor, Fiz 522 Micro and Nanofabrication Methods
2013/2
                Instructor, Fiz 524 Physics of Low-dimensional Semiconductors
2013/1
                Instructor, Fiz 522 Micro and Nanofabrication Methods
                Instructor, Fiz 524 Physics of Low-dimensional Semiconductors
2013/1
                Instructor, Fiz 522 Micro and Nanofabrication Methods
2012/1
Faculty of Science, Gazi University, Ankara, Turkey
2018/1
                Instructor, Fiz 123 Introduction to Nanotechnology
2017/1
                Instructor, Fiz 123 Introduction to Nanotechnology
                Instructor, Fiz 123 Introduction to Nanotechnology
2016/1
2015/1
                Instructor, Fiz 123 Introduction to Nanotechnology
                Advisor, Fiz 414 Research Project
2014/2
2014/1
                Advisor, Fiz 413 Research Project
                Instructor, Fiz 123 Introduction to Nanotechnology
2014/1
                Advisor, Fiz 413 Research Project
2013/1
2012/1
                Advisor, Fiz 413 Research Project (2 students)
                Instructor, Enf 102 Basic Computer Usage and Fortran Language (2 groups)
2011/2
                Advisor, Fiz 414 Research Project
2011/2
Faculty of Science and Arts, Gazi University, Ankara, Turkey
                Advisor, Fiz 414 Research Project
2018/2
2018/1
                Advisor, Fiz 413 Research Project
2011/1
                Advisor, Fiz 413 Research Project
                Advisor, Fiz 414 Research Project (2 students)
2009/2
2009/1
                Advisor, Fiz 413 Research Project (2 students)
Faculty of Engineering, Gazi University, Ankara, Turkey
2016/2
                Instructor, Fiz 104, Physics II (2 groups)
2015/2
                Instructor, Fiz 104, Physics II (2 groups)
                Instructor, Fiz 104, Physics II (2 groups)
2014/2
                Instructor, Fiz 104, Physics II (4 groups)
2013/2
                Instructor, Fiz 103 Physics I (3 groups)
2013/1
                Instructor, Fiz 103 Physics I (2 groups)
2012/1
                Instructor, Fiz 156 Physics Lab. (Mechanics)
2011/2
                Instructor, Fiz 104, Physics II (3 groups)
2011/2
                Instructor, Fiz 103 Physics I (3 groups)
2011/1
2009/2
                Instructor, Fiz 156 Physics Lab. (Mechanics)
                Instructor, Fiz 104, Physics II (2 groups)
2009/2
Faculty of Dentistry, Gazi University, Ankara, Turkey
2012/1
                Instructor, Fzk 111 Physics.
Faculty of Science at Polatli, Gazi University, Polatli, Ankara, Turkey
2012/1
                Instructor, Fiz 315 Properties of Matter.
Faculty of Technology, Gazi University, Ankara, Turkey
                Instructor, Fiz 104, Physics II (2 groups)
2019/2
2018/2
                Instructor, Fiz 104, Physics II
2017/2
                Instructor, Fiz 104, Physics II
                Instructor, Fiz 101 Physics I (2 groups).
2014/1
```

2011/1 Instructor, Fiz 101 Physics I.

Faculty of Technical Education, Gazi University, Ankara, Turkey

2011/1 Instructor, Fiz 101 Physics I. 2009/2 Instructor, Fiz 102 Physics II.

2009/1 Instructor, Fiz 101 Physics I (4 groups).

Turkish Military Academy, National Defense University, Ankara, Turkey

2018-2019 Instructor, Physics.

#### PROFESSIONAL ACTIVITIES

2019	Scientific Committee Member, VIII. ADIM Physics Days, 12-15 September,
	Bilecik, Turkey.
2018	Scientific Committee Member, VII. ADIM Physics Days, 23-25 May, Aydin,
	Turkey.
2017	Scientific Committee Member, VI. ADIM Physics Days, 19-21 July,
	Balikesir, Turkey.
2015	Scientific Committee Member, 1st International Conference on Organic
	Electronic Material Technologies (OEMT-2015) 25-28 March Elazig,
	Turkey.
2015	Scientific Committee Member, 2nd International Nanoscience and
	Nanotechnology for Next Generation (NaNoNG) 29-31 October Antalya,
	Turkey.
2011-2014	Member of board of management of the Photonics Research Center at Gazi
	University, Ankara, Turkey. <a href="http://fotonik.gazi.edu.tr">http://fotonik.gazi.edu.tr</a>
2004	Member of organizing group of 11th Condensed Matter Ankara Meeting at
	Gazi University, Ankara, Turkey.

### **PROFESSIONAL SERVICES**

Editorial Board Member

- PLOS ONE (SCI-indexed) (2013-2016, 2019-continue)
- Advances in Condensed Matter Physics (SCI-indexed) (2019-continue)
- Advances in OptoElectronics (ESCI-indexed) (2019)

### Issue Editor (SCI-indexed) (2016)

- Advances in Materials Science and Technology "Recent Progress in Group III-Nitride Electronic and Optoelectronic Devices"

# Reviewer (SCI-indexed)

- Journal of Physics D Applied Physics,
- Semiconductor Science and Technology,
- Nanotechnology,
- Diamond and Related Materials,
- Applied Physics Letters,
- Physica E: Low-dimensional Systems and Nanostructures,
- Physica B: Condensed Matter,
- AIP Advances,
- Computational Materials Science,
- Synthetic Metals,

### **PROFESSIONAL AFFILIATIONS**

2005-present	Senior Member, IEEE (Institute of Electrical and Electronics Engineers)
2005-present	Senior Member, IEEE Electron Devices Society
2006	Member, IEEE Communications Society
2006	Member, SPIE (Society of Photographic Instrumentation Engineers)
	Member, Hacettepe University Alumni

#### **SEMINARS**

12/2014	"Elektriksel Olarak Pompalanan Seyreltik Azotlu Dikey Kaviteli Yarıiletken
	Optik Yükselteç" Physics Department, Istanbul University, Istanbul, Turkey.
05/2008	"AlGaN/GaN-temelli Yüksek Elektron Hareketliliğine Sahip Transistörlerin
	(HEMTs) Elektron ve Manyeto-iletim Özelliklerinin İncelenmesi (in
	Turkish)", Department of Physics, Akdeniz University, Antalya, Turkey.
02/2008	"Investigation of 2DEG parameters in AlGaN/GaN based heterostructures
	using QMSA technique" Department of Computing and Electronic Systems,
	University of Essex, Colchester, UK.

## ATTENDED COURSES AND WORKSHOPS

01/2006	I. Adaligeli, "Solid State Educational Workshop 2006.1: The Theory of Spir		
	Transport (1 Week)" Feza Gürsey Institute, Istanbul, Turkey.		
01/2006	J. Schliemann, "Solid State Educational Workshop 2006.1: Rashba an		
Spin-Hall Effects in Quantum Dots (1 Week)" Feza Gürsey Ins			
	Istanbul, Turkey.		
01/2006	E.V. Sukhorukov, "Solid State Educational Workshop 2006.1: The Physics		
	of Quantum Shot Noise (1 Week)" Feza Gürsey Institute, Istanbul, Turkey.		
03-04/2005	R. Gerhardts, "Solid State Educational Workshop 2004.3-2:		
	Magnetotransport in low-dimensional systems (3 Weeks)", Bilkent		
	University, Ankara, Turkey.		

### **PUBLICATIONS**

Cites and h-index

Index name	Total cite	h-index
Web of Science	683	15
Google Scholar	899	16

# Books and Book Chapters

- 2 S. B. Lisesivdin, B. Sarikavak-Lisesivdin, E. Ozbay "Chapter 18: The Effects of the Interaction of Transition Metals on the Electronic Properties of the Graphene Nanosheets and Nanoribbons" Graphene Science Handbook Vol.3, CRCPress, Taylor&Francis, (2016).
- 1 E. L. Wolf, M. Medikonda, (Transl. eds: B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>) "Nanoteknoloji Devrimini Anlamak" Nobel Press, (2014).

#### SCI-Articles

- **69** E. Kutlu, P. Narin, A. Yildiz, <u>S. B. Lisesivdin</u> "Effects of Annealing under Different Atmospheres on Structural and Optical Properties of USCVD grown ZnO Nanostructures" *Mater. Sci. Eng. B* **254**, 114506 (2020).
- **68** R. Ibrahem, P. Narin, <u>S. B. Lisesivdin</u>, E. Ozbay "Investigation of electronic and optical properties of wurtzite MgZnO using GGA + U formalism", *Philos. Mag. Lett.* **99**, 424 (2019).
- 67 P. Narin, J. M. All Abbas, G. Atmaca, E. Kutlu, <u>S. B. Lisesivdin</u>, E. Ozbay "Ab initio study of electronic properties of armchair graphene nanoribbons passivated with heavy metal elements" *Solid State Commun.* **296**, 8 (2019).
- 66 P. Narin, E. Arslan, M. Ozturk, M. Ozturk, <u>S. B. Lisesivdin</u>, E. Ozbay "Scattering analysis of ultrathin barrier (< 7 nm) GaN-based heterostructures" *Appl. Phys. A: Mater. Sci. Process.* 125, 278 (2019).
- 65 J. M. All Abbas, P. Narin, E. Kutlu, S. B. Lisesivdin, E. Ozbay "Electronic properties of Zigzag ZnO nanoribbons with Hydrogen and Magnesium passivations" *Physica B* 556, (2019).
- 64 J.-H. Lee, J.-M. Ju, G. Atmaca, J.-G. Kim, S.-H. Kang, Y. S. Lee, S.-H. Lee, J.-W. Lim, H.-S. Kwon, S. B. Lisesivdin, J.-H. Lee "High Figure-of-Merit (V2BR/RON) AlGaN/GaN Power HEMT With Periodically C-Doped GaN Buffer and AlGaN Back Barrier" *IEEE J. Electron Dev. Soc.* 6, 1179 (2018).
- 63 Ö. Ömeroğlu, E. Kutlu, P. Narin, <u>S. B. Lisesivdin</u>, E. Ozbay "Electronic Properties of Graphene Nanoribbons Doped with Zinc, Cadmium, Mercury Atoms" *Physica E* **104**, 124 (2018).
- 62 G. Atmaca, P. Narin, E. Kutlu, T. V. Malin, V. G. Mansurov, K. S. Zhuravlev, S. B. Lisesivdin, E. Ozbay, "Negative Differential Resistance Observation and a New Fitting Model for Electron Drift Velocity in GaN-Based Heterostructures" *IEEE Trans. Electron Dev.* 65, 950 (2018).
- 61 P. Narin, E. Kutlu, G. Atmaca, A. Atilgan, A. Yildiz. <u>S. B. Lisesivdin</u>, "Structural and optical properties of hexagonal ZnO nanostructures grown by ultrasonic spray CVD" *Optik* 168, 86 (2018).
- **60** E. Kutlu, P. Narin, <u>S. B. Lisesivdin</u>, E. Ozbay "Electronic and optical properties of black phosphorus doped with Au, Sn and I atoms" *Philos. Mag.* **98**, 155 (2018).
- **59** P. Narin, E. Kutlu, G. Atmaca, <u>S. B. Lisesivdin</u>, E. Ozbay "A first principles investigation of the effect of aluminum, gallium and indium impurities on optical properties of β-Si<sub>3</sub>N<sub>4</sub> structure" *Optik* **147**, 115 (2017).
- **58** J. M. Al Abbas, P. Narin, G. Atmaca, E. Kutlu, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u> "The effect of doping in different layers on 2DEG for ultrathin-barrier AlN/GaN heterostructures" *Optoelectron. Adv. Mater.-Rapid Comm.* **11**, 328 (2017).

- 57 J. M. All Abbas, G. Atmaca, P. Narin, E. Kutlu, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u> "A Comparative Study of AlGaN and InGaN Back-Barriers in Ultrathin-Barrier AlN/GaN Heterostructures" *J. Elec. Mater.* 46, 5278 (2017).
- **56** E. Kutlu, P. Narin, G. Atmaca, B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Ozbay "Electronic structure of β-Si3N4 crystals with substitutional icosagen group impurities" J. Optoelectron. Adv. Mater. 19, 278 (2017).
- **55** P. Narin, E. Kutlu, B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Özbay "Electronic properties of Li-doped zigzag graphene nanoribbons" *Physica E* **84**, 543 (2016).
- **54** E. Kutlu, P. Narin, G. Atmaca, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, E. Özbay "Effect of substitutional As impurity on electrical and optical properties of β–Si3N4 Structure" *Mater. Res. Bull.* **83**, 128 (2016).
- **53** G. Atmaca, S. Ardali, E. Tiras, T. Malin, V. G. Mansurov, K. S. Zhuravlev, <u>S. B. Lisesivdin</u> "Scattering analysis of 2DEG mobility in undoped and doped AlGaN/AlN/GaN heterostructures with an *in situ* Si<sub>3</sub>N<sub>4</sub> passivation layer" *Solid-State Electron.* **118**, 12 (2016).
- **52** I. Kara, Y. Sarikavak, S. B. Lisesivdin, M. Kasap "Evaluation of Morphological and Chemical Differences of Gunshot Residues in Different Ammunitions Using SEM/EDS Technique" *Environ. Foren.* **17**, 68 (2016).
- **51** G. Atmaca, P. Narin, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u> "Two Dimensional Electron Gas in a Hybrid GaN/InGaN/ZnO Heterostructure with Ultrathin InGaN Channel Layer" *Physica E* **79**, 67 (2016).
- **50** G. Atmaca, S. Ardali, P. Narin, E. Kutlu, <u>S. B. Lisesivdin</u>, T. Malin, V. Mansurov, K. Zhuravlev, E. Tiras "Energy relaxation of hot electrons by LO phonon emission in AlGaN/AlN/GaN heterostructure with in situ Si3N4 passivation" *J. Alloys Compounds* **659**, 90 (2016).
- **49** S. Ardali, G. Atmaca, <u>S. B. Lisesivdin</u>, T. Malin, V. Mansurov, K. Zhuravlev, E. Tiras "The variation of temperature dependent carrier concentration and mobility in AlGaN/AlN/GaN heterostructure with SiN passivation" *Phys. Stat. Sol. B* **252**, 1960 (2015).
- **48** B. Sarikavak-Lisesivdin, S. B. Lisesivdin, N. Balkan, G. Atmaca, P. Narin, H. Cakmak, E. Ozbay "Energy relaxation of electrons in InGaN quantum wells" *Metall. Mater. Trans. A* **46**, 1565 (2015).
- **47** G. Atmaca, P. Narin, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, M. Kasap "Electron Transport Properties of Two Dimensional Electron Gas in Be<sub>x</sub>Zn<sub>1-x</sub>O/ZnO Heterostructures" *Philos. Mag.* **95**, 79 (2015).
- **46** G. Atmaca, P. Tasli, G. Karakoc, E. Yazbahar and <u>S. B. Lisesivdin</u> "Numerical Investigation of the 2DEG Properties of AlGaN/AlN/GaN HEMT Structures with InGaN/GaN MQW Back-Barrier Structure" *Physica E* **65**, 110 (2015).

- **45** O. Donmez, F. Sarcan, S. B. Lisesivdin, M. P. Vaughan, A. Erol, M. Gunes, M. C. Arikan, J. Puustinen and M. Guina, "Analytic modeling of temperature dependence of 2D carrier mobility in as-grown and annealed GaInNAs/GaAs quantum well structures" *Semicond. Sci. Technol.* **29**, 125009 (2014).
- 44 <u>S. B. Lisesivdin</u>, G. Atmaca, E. Arslan, S. Cakmakyapan, O. Kazar, S. Butun, Jawad-ul-Hassan, E. Janzén and E. Ozbay "Extraction and scattering analyses of 2D and bulk carriers in epitaxial graphene-on-SiC structure" *Physica E* **63**, 87 (2014).
- **43** E. Arslan, S. Cakmakyapan, O. Kazar, S. Bütün, <u>S. B. Lisesivdin</u>, N. A. Cinel, G. Ertas, S. Ardali, E. Tiras, J. Ul-Hassan, E.Janzén and Ekmel Özbay "SiC substrate effects on electron transport in the epitaxial Graphene layer" *Electron. Mater. Lett.* **10**, 387 (2014).
- **42** <u>S. B. Lisesivdin</u>, N. A. Khan, S. Mazzucato, N. Balkan, M. J. Adams, V.-M. Korpijärvi, M. Guina, G. Mezosi and M. Sorel "Optical gain in 1.3 μm electrically-driven dilute nitride VCSOAs" *Nanoscale Res. Lett.* **9**, 22 (2014).
- **41** K. Elibol, G. Atmaca, P. Tasli, <u>S. B. Lisesivdin</u> "A Numerical Study on Subband Structure of InxAl1-xN/GaN-Based HEMT Structures with Low-Indium (x<0.10) Barrier Layer" *Solid State Commun.* **162**, 8 (2013).
- **40** A. F. Kuloglu, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, E. Ozbay "First-principles calculations of Pd-terminated symmetrical armchair graphene nanoribbons" *Comp. Mater. Sci.* **68**, 18 (2013).
- **39** B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, E. Ozbay "The Effect of  $In_xGa_{1-x}N$  Back-barriers on the Dislocation Densities in  $Al_{0.31}Ga_{0.69}N/AlN/GaN/In_xGa_{1-x}N/GaN$  Heterostructures (0.05  $\leq$  x  $\leq$  0.14)" *Cur. Appl. Phys.* **13**, 224 (2013).
- **38** B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, E. Ozbay "Ab initio study of Ru-terminated and Ru-doped armchair graphene nanoribbons" *Mol. Phys.* **110**, 2295 (2012).
- **37** E. Tiras, O. Celik, S. Mutlu, S. Ardali, S. B. Lisesivdin, E. Ozbay "Temperature dependent energy relaxation time in AlGaN/AlN/GaN heterostructures" *Superlat. Microstruct.* **51**, 733 (2012).
- **36** O. Celik, E. Tiras, S. Ardali, <u>S. B. Lisesivdin</u>, E. Ozbay "Determination of the LO phonon energy by using electronic and optical methods in AlGaN/GaN" *Cent. Eur. J. Phys.* **10**, 485 (2012).
- **35** O. Kelekci, <u>S. B. Lisesivdin</u>, S.Ozcelik, E. Ozbay "Numerical optimization of In-mole fraction and layer thicknesses in Al<sub>x</sub>Ga<sub>1-x</sub>N/AlN/GaN high electron mobility transistors with InGaN back barrier" *Physica B* **406**, 1513 (2011).
- 34 A. Yildiz, P. Tasli, B. Sarikavak, <u>S. B. Lisesivdin</u>, M. K. Ozturk, M. Kasap, S. Ozcelik, E. Ozbay "Grain boundary related electrical transport in Al-rich Al<sub>x</sub>Ga<sub>1-x</sub>N layers grown by metal organic chemical vapor deposition" *Semiconductors* + 45, 33 (2011).
- **33** H. Yu, <u>S. B. Lisesivdin</u>, B. Bolukbas, O. Kelekci, M. K. Ozturk, S. Ozcelik, D. Caliskan, M. Ozturk, H. Cakmak, P. Demirel ve E. Ozbay "Improvement of breakdown characteristics in

- AlGaN/GaN/Al<sub>x</sub>Ga<sub>1-x</sub>N HEMT based on a grading Al<sub>x</sub>Ga<sub>1-x</sub>N buffer layer" *Phys. Stat. Sol. a* **207**, 2593 (2010).
- **32** P. Tasli, B. Sarikavak, G. Atmaca, K. Elibol, A. F. Kuloglu ve <u>S. B. Lisesivdin</u> "Numerical Simulation of Novel Ultrathin Barrier n-GaN/InAlN/AlN/GaN HEMT Structures: Effect of In Mole Fraction, Doping and Layer Thicknesses" *Physica B* **405**, 4020 (2010).
- **31** A. Bengi, <u>S. B. Lisesivdin</u>, M. Kasap, T. Mammadov, S. Ozcelik, E. Ozbay "Analysis of defect related optical transitions in AlGaN/GaN heterostructures" *Mater. Sci. Semicond. Process.* **13**, 105 (2010).
- **30** S. B. Lisesivdin, A. Yildiz, N. Balkan, M. Kasap, S. Ozcelik, E. Ozbay "Scattering Analysis of Two-dimensional Electrons in AlGaN/GaN with Bulk Related Parameters Extracted by Simple Parallel Conduction Extraction Method" *J. Appl. Phys.* **108**, 013712 (2010).
- **29** P. Tasli, A. Yildiz, M. Kasap, E. Ozbay, <u>S. B. Lisesivdin</u> ve S. Ozcelik "Contributions of the impurity band and electron–electron interactions to the magnetoconductance of AlGaN" *Philos. Mag.* **90**, 3591 (2010).
- **28** S. B. Lisesivdin, P. Tasli, M. Kasap, M. Ozturk, E. Arslan, S. Ozcelik, ve E. Ozbay, "Double subband occupation of the two-dimensional electron gas in In<sub>x</sub>Al<sub>1-x</sub>N/AlN/GaN/AlN Heterostructures with Low Indium Barrier (0.064 < x < 0.139)" *Thin Solid Films* **518**, 5572 (2010).
- 27 A. Yildiz, S. B. Lisesivdin, M. Kasap, D. Mardare "The substrate temperature dependent electrical properties of titanium dioxide thin films" *J. Mater. Sci.: Mater. Electron.* 21, 692 (2010).
- **26** S. Gokden, R. Tulek, A. Teke, J. H. Leach, Q. Fan, J. Xie, U. Ozgur, H. Morkoc, <u>S. B. Lisesivdin</u>, E. Ozbay "Mobility limiting scattering mechanisms in nitride-based two-dimensional heterostructures with InGaN channel" *Semicond. Sci. Technol.* **25**, 045024 (2010).
- 25 A. Yildiz, S. B. Lisesivdin, P. Tasli, E. Ozbay, ve M. Kasap "Determination of the critical indium composition corresponding to the metal-insulating transition in In<sub>x</sub>Ga<sub>1-x</sub>N (0.06 < x < 0.135) layers" *Curr. Appl. Phys.* 10, 838 (2010).
- **24** A. Yildiz, <u>S. B. Lisesivdin</u>, M. Kasap, S. Ozcelik, E. Ozbay ve N. Balkan "Investigation of low temperature electrical conduction mechanisms in highly resistive GaN bulk layers extracted with SPCEM" *Appl. Phys. A* **98**, 557 (2010).
- 23 P. Tasli, <u>S. B. Lisesivdin</u>, A. Yildiz, M. Kasap, E. Arslan, E. Özbay, ve S. Özcelik "Well parameters of the two-dimensional electron gas in Al<sub>0.88</sub>In<sub>0.12</sub>N/AlN/GaN/AlN heterostructures grown by MOCVD" *Cryst. Res. Tech.* **45**, 133 (2010).
- 22 <u>S. B. Lisesivdin</u>, E. Ozbay "Effect of various pseudomorphic AlN layer insertions on the electron densities of two-dimensional electron gas in lattice-matched In<sub>0.18</sub>Al<sub>0.82</sub>N/GaN based heterostructures" *Optoelectron. Adv. Mater.: Rapid. Comm.* **3**, 904 (2009).

- **21** A. Yildiz, <u>S. B. Lisesivdin</u>, H. Altuntas, M. Kasap ve S. Ozcelik "Electrical conduction properties of Si δ-doped GaAs grown by MBE" *Physica B* **404**, 4202 (2009).
- **20** G. Atmaca, K. Elibol, <u>S. B. Lisesivdin</u>, M. Kasap, E. Ozbay "Numerical optimization of Almole fractions and layer thicknesses in normally-on AlGaN-GaN double-channel high electron mobility transistors (DCHEMTs)" *J. Optoelectron. Adv. Mater.* **11**, 578 (2009).
- **19** A. Teke, S. Gökden, R. Tülek, J. H. Leach, Q. Fan, J. Xie, Ü. Özgür, H. Morkoç, <u>S. B. Lisesivdin</u>, E. Özbay, "The effect of AlN interlayer thicknesses on scattering processes in lattice-matched AlInN/GaN two-dimensional electron gas heterostructures "*New J. Phys.* **11**, 063031 (2009).
- 18 S. B. Lisesivdin, N. Balkan, O. Makarovsky, A. Patanè, A. Yildiz, M. D. Caliskan, M. Kasap, S. Ozcelik, E. Ozbay "Large Zero-Field Spin Splitting in AlGaN/AlN/GaN/AlN Heterostructures" *J. Appl. Phys.* 105, 093701 (2009).
- 17 S. B. Lisesivdin, H. Altuntas, A. Yildiz, M. Kasap, E. Ozbay, S. Ozcelik, "DX-center Energy Calculation with Quantitative Mobility Spectrum Analysis in n-AlGaAs/GaAs Structures with Low Al Content" *Superlatt. Microstruct.* 45, 604 (2009).
- **16** A. Yildiz, <u>S. B. Lisesivdin</u>, M. Kasap, D. Mardare "Non-adiabatic Small Polaron Hopping Conduction in Nb-doped TiO<sub>2</sub> thin films" *Physica B* **404**, 1423 (2009).
- **15** Y. Sun, N. Balkan, M. Aslan, <u>S. B. Lisesivdin</u>, H. Carrere, M. C. Arikan, X. Marie "Electronic transport in n- and p-type modulation doped Ga<sub>x</sub>In<sub>1-x</sub>N<sub>y</sub>As<sub>1-y</sub>/GaAs Quantum Wells" *J. Phys: Condens. Matt.* **21**, 174210 (2009) Invited Article.
- 14 S. B. Lisesivdin, N. Balkan, E. Ozbay "A Simple Parallel Conduction Extraction Method (SPCEM) for MODFETs and Undoped GaN-based HEMTs" *Microelectron. J.* 40, 413 (2009).
- 13 A. Yildiz, S. B. Lisesivdin, M. Kasap, M. Bosi "Anomalous temperature dependence of the electrical resistivity in In<sub>0.17</sub>Ga<sub>0.83</sub>N" *Solid State Commun.* **149**, 337 (2009).
- **12** A. Yildiz, S. B. Lisesivdin, M. Kasap, D. Mardare "Electrical Properties of TiO<sub>2</sub> Thin Films" *J. Non-Crys. Solids* **354**, 4944 (2008).
- 11 <u>S. B. Lisesivdin</u>, S. Demirezen, M. D. Caliskan, A. Yildiz, M. Kasap, S. Ozcelik ve E. Ozbay "Growth parameters investigation of Al<sub>0.25</sub>Ga<sub>0.75</sub>N/GaN/AlN heterostructures with Hall Effect Measurements" *Semicond. Sci. Technol.* **23**, 095008 (2008).
- **10** E. Arslan, S. Butun, <u>S. B. Lisesivdin</u>, M. Kasap, S. Ozcelik, ve E. Ozbay "The persistent photoconductivity effect in AlGaN/GaN heterostructures grown on sapphire and SiC substrates" *J. Appl. Phys.* **103**, 103701 (2008).
- 9 S. Acar, S. B. Lisesivdin, M. Kasap, S. Ozcelik ve E. Ozbay "Determination of two-dimensional electron and hole gas carriers in AlGaN/GaN/AlN heterostructures grown by Metal Organic Chemical Vapor Deposition" *Thin Solid Films* **516**, 2041 (2008).

- **8** A. Yildiz, F. Dagdelen, S. Acar, <u>S. B. Lisesivdin</u>, M. Kasap, Y. Aydogdu ve M. Bosi "Stokes shift and bandgap bowing in  $In_xGa_{1-x}N$  (0.060  $\le x \le 0.105$ ) grown by MOVPE" *Acta Physica Pol.* (a) **113**, 731 (2008).
- 7 <u>S. B. Lisesivdin</u>, E. Arslan, M. Kasap, S. Ozcelik ve E. Ozbay, "Self-consistent scattering analysis of Al<sub>0.2</sub>Ga<sub>0.8</sub>N/AlN/GaN/AlN heterostructures grown on 6H-SiC substrates using photo-Hall effect measurements" *J. Phys.: Condens. Matt.* **20**, 045208 (2008).
- 6 <u>S. B. Lisesivdin</u>, A. Yildiz ve M. Kasap, "Optimization of alloy composition, interlayer and barrier thicknesses in Al<sub>x</sub>Ga<sub>1-x</sub>N/(AlN)/GaN high electron mobility transistors" *Opt. Adv. Mater.-Rapid Comm.* **1** (9), 467 (2007).
- 5 A. Yildiz, S. B. Lisesivdin, M. Kasap, D. Mardare "High temperature variable-range hopping conductivity in undoped TiO<sub>2</sub> thin film" *Opt. Adv. Mater.-Rapid Comm.* 1 (10), 531 (2007).
- 4 A. Yildiz, S. B. Lisesivdin, S. Acar, M. Kasap ve M. Bosi, "Electron transport in Ga-rich In<sub>x</sub>Ga<sub>1-x</sub>N alloys" *Chin. Phys. Lett.* **24**, 2930 (2007).
- 3 S. B. Lisesivdin, A. Yildiz, S. Acar, M. Kasap, S. Ozcelik ve E. Ozbay "The Effect of Strain Relaxation on Electron Transport in Undoped Al<sub>0.25</sub>Ga<sub>0.75</sub>N/GaN HEMT Structures" *Physica B* 399 (2), 132 (2007).
- 2 S. B. Lisesivdin, A. Yildiz, S. Acar, M. Kasap, S. Ozcelik ve E. Ozbay "Electronic Transport Characterization of AlGaN/GaN HEMT Structures grown by MOCVD" *Appl. Phys. Lett.* **91**, 102113 (2007). Selected for *Virtual Journal of Nanoscale Science & Technology* **16** 12 (2007).
- 1 S. B. Lisesivdin, S. Acar, M. Kasap, S. Ozcelik, S. Gokden ve E. Ozbay "Scattering Analysis of Extracted 2D carrier in AlGaN/GaN HEMT Structures" *Semicond. Sci. Technol.* 22, 543 (2007).

### SCI Technical Notes

1 I. Kara, S. B. Lisesivdin, M. Kasap, E. Er, U. Uzek "The Relationship between the Surface Morphology and Chemical Composition of Gunshot Residue Particles" *J. Foren. Sci.* **60**, 1030 (2015).

### Non-SCI Articles

1 O. Celik, E. Tiras, S. Ardali, S. B. Lisesivdin, E.Ozbay "Determination of the in-plane effective mass and quantum lifetime of 2D electrons in AlGaN/GaN based HEMTs" *Phys. Stat. Sol.* (c) 8, 1625 (2011).

#### **Proceedings**

- 90 S. B. Lisesivdin, J. Lang, F. Jelezko "Spin-coherence time measurements of NV- centers in  $_{15}N^+$ ,  $_{15}N_2^+$  and O<sup>+</sup> implanted diamond" *Quantum Optics and Informatics Meeting* 4 (Kobit 4), İzmir (2020).
- 89 B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Ozbay, F. Jelezko "Spin-polarized DFT calculations of nitrogen-vacancy color centers in diamond with various XC potentials" *Quantum Optics and Informatics Meeting* 4 (Kobit 4), İzmir (2020).
- **88** O. Omeroglu, S. B. Lisesivdin, E. Ozbay "The Optical Properties of Group-III Nitrides with LDA-1/2 Approximation" 20<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara, P78, (2018).
- **87** G. Atmaca, P. Narin, E. Kutlu, S. Ardali, E. Tiras, T. Malin, V. G. Mansurov, K. S. Zhuravlev, S. B. Lisesivdin, E. Ozbay "An Investigation on Lifetime of Hot Phonons in GaN-Based Heterostructures" *20<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara*, P68, (2018).
- **86** J. M. All Abbas, P. Narin, E. Kutlu, <u>S. B. Lisesivdin</u>, E. Ozbay "First Principle Study of ZnO Nanoribbon Passivated with H and Mg" *20<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara*, P37, (2018).
- 85 E. Kutlu, P. Narin, A. Yildiz, <u>S. B. Lisesivdin</u> "Structural and Optical Properties of Mg<sub>x</sub>Zn<sub>1-x</sub>O Nanostructures Depending on Growth Temperatures" 20<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara, P31, (2018).
- **84** E. Kutlu, P. Narin, A. Yildiz, S. B. Lisesivdin "Effect of Transducer Power on Optical and Structural Properties of ZnO Nanostructures" 20<sup>th</sup> National Workshop on Optics, Electrooptics and Photonics, Ankara, P30, (2018).
- 83 P. Narin, E. Kutlu, S. B. Lisesivdin, E. Ozbay "Growth of ZnO Nanostructures on Sapphire by Ultrasonic Spray CVD" 20<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara, P29, (2018).
- **82** P. Narin, E. Kutlu, <u>S. B. Lisesivdin</u>, "Optical and Structural Properties of ZnO Grown by Mist CVD Using Different Precursor Molarity" *20<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara*, P28, (2018).
- **81** R. Ibrahem, P. Narin, S. B. Lisesivdin, E. Ozbay "First-Principles Calculation of Optical Properties of Magnesium Zinc Oxide" 20<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara, P14, (2018).
- **80** O. Omeroglu, <u>S. B. Lisesivdin</u>, E. Ozbay "The Electronic Properties of Asymmetrical Armchair Boron Nitride Nanoribbons With Germanium Termination" p475, *Turkish Physical Society 34<sup>th</sup> International Physics Congress*, September 5-9 2018, Bodrum, Turkey.
- 79 O. Omeroglu, S. B. Lisesivdin, E. Ozbay "Improvement of the Theoretical Band Gaps for AlN, GaN and InN with LDA-1/2 Approach" p495, *Turkish Physical Society 34<sup>th</sup> International Physics Congress*, September 5-9 2018, Bodrum, Turkey.

- **78** M. T. Haliloglu, <u>S. B. Lisesivdin</u>, E. Ozbay "Back-Side Via Etching Application of SiC for GaN-Based Transistors" *I*<sup>st</sup> *Light and Light-Based Technologies Workshop*, Ankara, p51 (2018).
- 77 S. Mutlu, S. B. Lisesivdin, A. Erol, E. Tiras "Evolution of HELLISH devices: Colorful story of HELLISH Devices from IR to VIS light" *Celebrating Naci:The Physics of Optoelectronic Materials and Devices*, 27-28 March 2017, Colchester, UK.
- **76** A. Erol, S. Mutlu, <u>S. B. Lisesivdin</u>, E. Tiras, "Hot electron Transport Based Devices for Optoelectronics" *International Conference on Condensed Matter and Material Science*, October 11-15 2017, Adana, Turkey.
- 75 S. B. Lisesivdin, E. Kutlu, J. M. Allabbas, O. Omeroglu, R. Ibrahem, E. Ozbay "Zn ve Cd Atomları ile Katkılanmış "Armchair" Grafen Nanoşeritlerin Elektronik Yapıları" *ADIM Physics Days VI*, July 19-21 2017, Balikesir, Turkey.
- 74 J.-H. Lee, G. Atmaca, J. -G. Kim, D. -H. Son, J. -M. Ju, <u>S. B. Lisesivdin</u>, J. -H. Lee, High Voltage Low Leakage Current AlGaN/GaN HEMTs with Multi-layer Buffer and AlGaN Back-Barrier Structure, P310, *Turkish Physical Society 33<sup>rd</sup> International Physics Congress*, September 6-10 2017, Bodrum, Turkey.
- 73 J. M. Al Abbas, P. Narin, S. B. Lisesivdin, E. Ozbay, A First Principle Investigations of The Electronic Structures For ZGNRs Terminated With Zn, Cd and H, P587, *Turkish Physical Society 33<sup>rd</sup> International Physics Congress*, September 6-10 2017, Bodrum, Turkey.
- 72 A. F. Kuloglu, <u>S. B. Lisesivdin</u>, E. Ozbay, A Theoretical Study of (5,0) Zigzag BexZn1-Xo Nanotubes: Investigation of Structural, Electronic and Optic Properties Using Density Functional Theory, P588, *Turkish Physical Society 33<sup>rd</sup> International Physics Congress*, September 6-10 2017, Bodrum, Turkey.
- 71 E. Kutlu, O. Omeroglu, R. Ibrahem, <u>S. B. Lisesivdin</u>, E. Ozbay, First Principle Calculations of Zn and Cd-Doped Zigzag Graphene Nanoribbons, P611, *Turkish Physical Society 33<sup>rd</sup> International Physics Congress*, September 6-10 2017, Bodrum, Turkey.
- **70** O. Omeroglu, E. Kutlu, <u>S. B. Lisesivdin</u>, E. Ozbay, Investigation of The Electronic Properties of Zinc and Magnesium Adsorption on Graphene Sheets, P620, *Turkish Physical Society 33<sup>rd</sup> International Physics Congress*, September 6-10 2017, Bodrum, Turkey.
- **69** G. Atmaca, J. -G. Kim, J. -H. Lee, C. -H. Won, S. -H. Kang, S. B. Lisesivdin, J. -H. Lee, Numerical Optimization of 2DEG Improvement in AlGaN/GaN HEMTs with C-GaN/u-GaN Multi-layer Buffer Structure, P629, *Turkish Physical Society 33<sup>rd</sup> International Physics Congress*, September 6-10 2017, Bodrum, Turkey.
- **68** R. Ibrahem, P. Narin, S. B. Lisesivdin, E. Ozbay, Optimized Ab Initio Studies on Electronic Structure of Wurtzite MgZnO, P630, *Turkish Physical Society 33<sup>rd</sup> International Physics Congress*, September 6-10 2017, Bodrum, Turkey.
- 67 P. Narin, J. M. Al Abbas, <u>S. B. Lisesivdin</u>, E. Ozbay, The Effect of Zinc, Cadmium and Hydrogen Terminations on The Electronic Structure of Symetrical AGNRs, P648, *Turkish Physical Society 33<sup>rd</sup> International Physics Congress*, September 6-10 2017, Bodrum, Turkey.

- **66** E. Kutlu, P. Narin, G. Atmaca, <u>S. B. Lisesivdin</u>, E. Ozbay "Sn, I, Au gibi Bazı Safsızlıkların Siyah Fosfor'un Elektronik ve Optik Özelliklerine Etkileri" *18<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara*, P26,(2016).
- 65 P. Narin, E. Kutlu, G. Atmaca, B. Sarıkavak-Lisesivdin, <u>S. B. Lisesivdin</u>, E. Ozbay "Ultraince Bariyere Sahip AlN/GaN ve InAlN/GaN HEMT Yapıların Yapısal ve Yüzey Özelliklerinin İncelenmesi" *18<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara*, P72, (2016).
- 64 G. Atmaca I. Berkutov, O. A. Mironov, K. Rogacki, S. B. Lisesivdin, E. Ozbay "The Weak Localization In A Two-Dimensional Electon Gas In AlInN/AlN/GaN Heterostructures" 18<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara, P43,(2016).
- 63 J. M. Al Abbas, G. Atmaca, P. Narin, E. Kutlu, B. Sarikavak-Lisesivdin, S. B. Lisesivdin "Numerical Investigation Of 2DEG Properties In Ultrathin-Barrier AlN/GaN Heterostructures with AlGaN and InGaN Back-Barriers" 18<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara, P47,(2016).
- **62** M. Ozturk, E. Arslan, P. Narin, <u>S. B. Lisesivdin</u>, B. Sarikavak-Lisesivdin, E. Ozbay "Ultraince Bariyerli GaN-Temelli HEMT'lerde Elektron Gazının Elektriksel Özellikleri ve Saçılma Analizleri" *18<sup>th</sup> National Workshop on Optics, Electro-optics and Photonics, Ankara*, P50,(2016).
- **61** J. M. Al Abbas, P. Narin, E. Kutlu, G. Atmaca, <u>S. B. Lisesivdin</u>, B. Sarikavak-Lisesivdin "Ptipi ve N-tipi InGaN Arka-Bariyerli Ultraince AlInN/GaN Çoklu Yapılarda İki Boyutlu Elektron Gazı" *ADIM Physics Congress V*, p.163 (2016).
- **60** J. M. Al Abbas, P. Narin, G. Atmaca, E. Kutlu, <u>S. B. Lisesivdin</u>, B. Sarikavak-Lisesivdin "Ultraince Bariyerli AlN/GaN Çoklu Yapılarda Farklı Katmanların 2BEG Üzerine Etkisi" *ADIM Physics Congress V*, p.164 (2016).
- **59** E. Kutlu, P. Narin, G. Atmaca, J. M. Al Abbas, B. Sarikavak Lisesivdin, <u>S. B. Lisesivdin</u> "Li Katkılı Zigzag Kenarlı Grafen Nano Şeritlerin Elektronik Özelliklerinin İncelenmesi" *ADIM Physics Congress V*, p.151 (2016).
- **58** E. Tiras, G. Atmaca, S. B. Lisesivdin, S. Ardali, T. Malin, V. Mansurov, K. Zhuravlev, Power-loss Mechanisms in Surface Passivated AlGaN/AlN/GaN Heterojunctions, 11<sup>th</sup> Conference on Laser and Electro-Optic Pacific Rim, CLEO-PR 2015, 24-28 August, Busan, Korea (2015).
- 57 S. Ardali, G. Atmaca, <u>S. B. Lisesivdin</u>, T. Malin, V. Mansurov, K. Zhuravlev, E. Tiras, Surface Passivation Effect in AlGaN/AlN/GaN Heterostructure, *European Materials Research Society 2015 Spring Meeting*, I-P1 3 (2015).
- **56** T. Tiras, G. Atmaca, <u>S. B. Lisesivdin</u>, T. Malin, V. Mansurov, K. Zhuravlev, E. Tiras, The longitudinal optical phonon energy in passivated AlGaN/AlN/GaN, *European Materials Research Society 2015 Spring Meeting*, I-P1 5 (2015).

- 55 P. Narin, E. Kutlu, G. Atmaca, B, Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, "Investigation of Optical Properties of the Beta-Si3N4 structure doped with some Group IIIA Elements" *Ist International Conference on Organic Electronic Material Technologies*, p102 (2015).
- **54** E. Kutlu, P. Narin, G. Atmaca, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u> "First Principle Calculations of Electrical Properties of Insulator Wurtzite the Beta-Si3N4 with the Aluminum, Indium and Gallium Impurities" *Ist International Conference on Organic Electronic Material Technologies*, p103 (2015).
- 53 G. Atmaca, T. Malin, E. Kutlu, S. Ardali, P. Narin, V. Mansurov, B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Tiras, K. Zhuravlev, "The Effect of In-Situ Si3N4 Passivation on Hot-Electron Energy Relaxation Rates in AlGaN/GaN Heterostructures" Нитриды галлия, индия и алюминия: структуры и приборы, Санкт-Петербурге, p141-142 (2015)
- **52** G. Atmaca, P. Narin, E. Kutlu, <u>S. B. Lisesivdin</u> "The Effect of Si<sub>3</sub>N<sub>4</sub> Passivation with As-Impurity on the Device Properties of AlGaN/GaN HEMT Structures" *IX. International Balkan Physics Union Conference*, p410 (2015).
- **51** <u>S. B. Lisesivdin</u>, G. Atmaca, S. Ardali, E. Tiras, T. Malin, V. Mansurov, K. Zhuravlev "The Effect of in situ Si<sub>3</sub>N<sub>4</sub> Passivation on 2DEG Quantum Well Parameters in AlGaN/GaN Heterostructures *IX. International Balkan Physics Union Conference*, p441 (2015).
- 50 <u>S. B. Lisesivdin</u>, "Implementation of Simple Parallel Conduction Extraction Method (SPCEM) for seperating 2D and 3D conduction channels in semiconductor structures" Конференция И Школа Молодых Учёных По Актуальным Проблемам Физики Полупроводниковых Структур, Novosibirsk, 25, (2014).
- **49** E. Kutlu, P. Narin, G. Atmaca, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u> "Ab initio study of oxygen and arsenic impurities on non-linear optical properties of β–Si<sub>3</sub>N<sub>4</sub> material" Конференция И Школа Молодых Учёных По Актуальным Проблемам Физики Полупроводниковых Структур, Novosibirsk, 77, (2014).
- **48** G. Atmaca, A. E. Evrensel, <u>S. B. Lisesivdin</u> "Influence of interface traps on device performance of AlGaN/GaN HEMTS with Si<sub>3</sub>N<sub>4</sub> passivation" *Turkish Physical Society 31<sup>th</sup> International Physics Congress*, p371 (2014).
- 47 E. Kutlu, P.Narin, G. Atmaca, <u>S. B. Lisesivdin</u>, M. Kasap "Investigation of electrical properties of two dimensional hole gas in hybrid InGaN/ZnO heterotructure" *Turkish Physical Society 31<sup>th</sup> International Physics Congress*, p401 (2014).
- **46** S. B. Lisesivdin, E. Kutlu, P. Narin, G. Atmaca, B. Sarikavak-Lisesivdin, "Investigation of the effect of the arsenic impurity on the electronic and optical properties of β–Si<sub>3</sub>N<sub>4</sub> dielectric material" *Turkish Physical Society 31<sup>th</sup> International Physics Congress*, p402 (2014).
- **45** P. Narin, G. Atmaca, <u>S. B. Lisesivdin</u>, "Effects of ultrathin InGaN channel layer on two dimensional electron gas in hybrid GaN/InGaN/ZnO heterostructures" *Turkish Physical Society 31<sup>th</sup> International Physics Congress*, p406 (2014).

- **44** <u>S. B. Lisesivdin</u>, G. Atmaca, E. Arslan, J. Ul-Hassan, E. Janzén, E. Ozbay "SiC üzerine büyütülen grafen yapılarda elektriksel iletim kanallarının ayrıştırılıp incelenmesi *XIX. Solid State Matter Physics Ankara Meeting*, S13, (2013). [Invited].
- 43 S. B. Lisesivdin, N. A. Khan, S. Mazzucato, N. Balkan, M. J. Adams "Gain in electrically-driven 1.3 μm dilute nitride VCSOAs" *COST MP0805 Final Meeting, Istanbul*, P17, (2013).
- **42** P. Narin, G. Atmaca, E. Boyali, <u>S. B. Lisesivdin</u>, M. Kasap, S. Ozcelik, "Scattering Analysis of 2DEG in AlInN/GaN Based Heterostructures with GaN and InGaN Quantum Wells", *Turkish Physical Society* 30<sup>th</sup> International Physics Congress, p530 (2013).
- **41** E. Boyali, P. Narin, G. Atmaca, <u>S. B. Lisesivdin</u>, M. Kasap and S. Ozcelik, "The Investigation of Temperature Dependent Electrical Transport Properties of In<sub>x</sub>Ga<sub>1-x</sub>P/GaAs", *Turkish Physical Society 30<sup>th</sup> International Physics Congress*, p482 (2013).
- **40** P. Narin, G. Atmaca, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, M. Kasap, "A Numerical Investigation on Electronic Properties of Two Dimensional Electron Gas in Be<sub>x</sub>Zn<sub>1-x</sub>O/ZnO Heterostructures", *Turkish Physical Society 30<sup>th</sup> International Physics Congress*, p529 (2013).
- **39** G. Atmaca, P. Tunay Tasli, S. B. Lisesivdin, "Electron Confinement in Lattice-Matched InAlN/AlN/GaN Heterostructures with Al<sub>y</sub>Ga<sub>1-y</sub>N Back-barrier", 8<sup>th</sup> Nanoscience and Nanotechnology Conference, PP-332 (2012).
- **38** B. Sarikavak Lisesivdin, S. B. Lisesivdin, E. Ozbay, "First Principles Study of Interaction Between Ru and Graphene Nanoribbons" 2<sup>nd</sup> Int. Conf. on Comp. for Sci. and Techno. pp-70 (2012).
- 37 P. Tasli, S. B. Lisesivdin, M. Kasap, S. Ozcelik, E. Ozbay "InAlN/GaN Temelli Yuksek Elektron Mobiliteli Transistörlerin (HEMT) Elektron ve Magneto Iletim Ozellikleri" *ADIM Physics Congress II*, 65 (2012).
- **36** B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, E. Ozbay "AlGaN/GaN-temelli Yuksek Hareketlilige Sahip Transistorlerde InGaN Geribariyerin Dislokasyon Yogunluguna Etkisi" *ADIM Physics Congress II*, 131 (2012).
- **35** A. F. Kuloglu, B. Alsancak, C. Gunes, <u>S. B. Lisesivdin</u>, E. Ozbay "Kenarlari Paladyum Atomlari ile Sonlandirilmis Farkli Genisliklerdeki Armchair Grafen Nanoseritlerin Elektronik Ozelliklerinin Yogunluk Fonksiyonu Teorisi Kullanilarak Incelenmesi" *I. Solid State Matter Physics İzmir Meeting*, p01 (2012).
- **34** C. Günes, A. F. Kuloglu, <u>S. B. Lisesivdin</u>, E. Ozbay, "GaN-tabanli HEMT Yapilarin Hareketliligi ve Tasiyici Yogunlugunun Deneysel Incelenmesi" *I. Solid State Matter Physics İzmir Meeting*, p18 (2012).
- **33** K. Elibol, C. Gunes, A. F. Kuloglu, E. Boyali and <u>S. B. Lisesivdin</u> "A Numerical Study on Effects of InAlN/AlGaN Barrier in InAlN/AlGaN/AlN/GaN-based High Electron Mobility Transistors" *Turkish Physical Society XXVIII. International Conference*, p711 (2011).

- **32** K. Elibol, G. Atmaca, O. Kelekci, P. Tasli, E. Ozbay and <u>S. B. Lisesivdin</u> "Self-consistent Transport Properties of Graphene Sheets" *Turkish Physical Society XXVIII. International Conference*, p710 (2011).
- **31** G. Karakoc, G. Atmaca, E. Yazbahar, P. Tasli and <u>S. B. Lisesivdin</u> "Numerical Investigation of Two-dimensional Electron Gas in AlGaN/AlN/GaN HEMT with InGaN/GaN Multiquantum Well Structure" *Turkish Physical Society XXVIII. International Conference*, p745 (2011).
- **30** K. Elibol, Ö. Kelekçi, G. Atmaca, <u>S. B. Lişesivdin</u>, M. Kasap, S. Özçelik and E. Özbay "Grafen Flake Üretim Yöntemlerinin Geliştirilmesi" *XVII. Solid State Matter Physics Ankara Meeting*, S2 (2010).
- **29** G. Atmaca, K. Elibol, P. Taşlı, <u>S. B. Lişesivdin</u> and M. Kasap "Eklem Alan Etkili Transistörlerin Elektriksel Karakteristiklerinin İncelenmesi" *XVII. Solid State Matter Physics Ankara Meeting*, S12 (2010).
- **28** Ö. Kelekçi, <u>S. B. Lişesivdin</u>, M. Kasap, S. Özçelik and E. Özbay "InGaN arka bariyerli Al<sub>x</sub>Ga<sub>1-x</sub>N/AlN/GaN HEMT yapılarındaki ince filmlerin alaşım oranları ve kalınlıklarının nümerik optimizasyonu" *XVII. Solid State Matter Physics Ankara Meeting*, S17 (2010).
- 27 K. Elibol, G. Atmaca, P. Taşlı, <u>S. B. Lişesivdin</u> and M. Kasap "GaN Tabanlı MESFET Yapıların 2-boyutta Elektriksel Karakteristikleri" *XVII. Solid State Matter Physics Ankara Meeting*, P34 (2010).
- **26** A. F. Kuloglu, <u>S. B. Lişesivdin</u> and M. Kasap "GaAs Tabanlı Bir MOSFET Yapının 2-Boyutta Akım Gerilim Karakteristiklerinin İncelenmesi" *XVII. Solid State Matter Physics Ankara Meeting*, P88 (2010).
- **25** O. Kartaloğlu, G. Atmaca, K. Elibol and <u>S. B. Lişesivdin</u> "Erbiyum Katkılı Eklem Diyotun I-V Karakteristiği" *XVII. Solid State Matter Physics Ankara Meeting*, P46 (2010).
- 24 H. Yu, S. Lisesivdin, B. Bolukbas, O. Kelekci, M. Ozturk, H. Cakmak, P. Demirel and E. Ozbay "Double Heterostructure AlGaN/GaN/AlGaN HEMT Based on Grading AlGaN/AlN Buffer Layer", 2009 MRS Fall Meeting, I: III-Nitride Materials for Sensing, Energy Conversion, and Controlled Light-Matter Interactions, SESSION 14: Surface and Interface Properties II, 14.9 (2009).
- **23** A. Ilgaz, S. Gokden, A. Teke, S. Ozcelik, <u>S. B. Lisesivdin</u>, E. Ozbay "Safir ve SiC Uzerine Buyutulmus AlGaN/AlN/GaN HEMT Yapilarindaki Sicak Elektron Dinamiginin Karsilastirilmasi" *XVI. Solid State Matter Physics Ankara Meeting*, P73 (2009).
- **22** G. Atmaca, K. Elibol, P. Tasli, <u>S. B. Lisesivdin</u>, M. Kasap "Cift kanalli AlGaAs/InGaAs/GaAs tabanli p-HEMT Yapilarinda 1 ve 2-boyutta Schrödinger-Poisson Cozumleri ve Akim-Gerilim Incelemeleri" *XVI. Solid State Matter Physics Ankara Meeting*, P59 (2009).
- 21 <u>S. B. Lisesivdin</u>, H. Altuntaş, A. Yıldız, M. Kasap, E. Ozbay, S. Ozcelik "Sicakliga ve manyetik alana bagli Hall olcumlerinin analizi ile DX-merkezi aktivasyon enerjisi hesabi" *XVI. Solid State Matter Physics Ankara Meeting*, S9 (2009).

- **20** P. Tasli, <u>S. B. Lisesivdin</u>, A. Yildiz, M. Kasap, E. Ozbay "Determination of Two-Dimensional Electron and Hole Gas Carriers in Al<sub>0.88</sub>In<sub>0.12</sub>N/GaN-based Heterostructures Grown by Metal Organic Chemical Vapor Deposition" *Turkish Physical Society XXVI. International Conference*, p510 (2009).
- 19 P. Tasli, S. B. Lisesivdin, M. Kasap, K. Elibol, G. Atmaca, E. Ozbay "A Numerical Study on Subband Structure of Al<sub>x</sub>In<sub>1-x</sub>N/GaN-based HEMT Structures with Low-Indium (x>0.82) Barrier Layer" *Turkish Physical Society XXVI. International Conference*, p509 (2009).
- **18** A. Yildiz, <u>S. B. Lisesivdin</u>, M. Kasap, S. Özçelik, D. Mardare "Small Polaron Transport In Titanium Dioxide Thin Film" *Turkish Physical Society XXV. International Conference*, p133 (2008).
- 17 <u>S. B. Lisesivdin</u>, N. Balkan, O. Makarovsky, A. Patanè, A. Yildiz, M. D. Caliskan, M. Kasap, S. Ozcelik, E. Ozbay "Investigation of the Beating Pattern of Shubnikov-De Haas Oscillations and Spin Splitting in AlGaN/AlN/GaN/AlN Heterostructures" *Turkish Physical Society XXV. International Conference*, p484 (2008).
- 16 K. Elibol, G. Atmaca, S. B. Lişesivdin, M. Kasap, S. Özçelik "Optimization of Al-mole Fraction and Layer Thicknesses in Al<sub>x</sub>Ga<sub>1-x</sub>N/AlN/GaN/Al<sub>x</sub>Ga<sub>1-x</sub>N/AlN/GaN Double Channel HEMT Structures" *Turkish Physical Society XXV. International Conference*, p454 (2008).
- 15 S. B. Lisesivdin, N. Balkan, E. Ozbay, "A Simple Parallel Conduction Extraction Method for MODFET's and Undoped GaN-based HEMTs" Workshop on Recent Advances of Low Dimensional Structures and Devices, p90 (2008).
- 14 A. Yildiz, S. Eker, <u>S. B. Lisesivdin</u>, M. Kasap, S. Ozcelik, D. Mardare "On the conduction mechanism of TiO2" 8th International Conference on Physics of Advanced Materials, p28 (2008).
- **13** A. Yildiz, H. Altuntas, <u>S. B. Lisesivdin</u>, A. Bengi and M. Kasap "Stokes shift in In<sub>0.13</sub>Ga<sub>0.87</sub>N epitaxial layer grown by MOVPE" *Turkish Physical Society XXIV. International Conference*, p152 (2007).
- 12 H. Altuntas, S. B. Lisesivdin, A. Yildiz, T. Mammedov and S.Ozcelik "MBE Growth and Characterization of n-AlGaAs/GaAs Heterojunction" *Turkish Physical Society XXIV. International Conference*, p414 (2007).
- 11 <u>S. B. Lisesivdin</u>, A. Yildiz, S. Acar, M. Kasap, S. Ozcelik, S. Gokden, E. Ozbay "Improved Scattering Analysis of 2DEG carriers in Al<sub>0.25</sub>Ga<sub>0.75</sub>N/GaN Heterostructures" *NanoTr3 Conference Proceedings*, p134 (2007).
- **10** A. Yildiz, <u>S. B. Lisesivdin</u>, S. Acar, M. Kasap and D. Mardare "Electrical Conductivity Behaviour in Anatase Phase TiO<sub>2</sub>" *NanoTr3 Conference Proceedings*, p151 (2007).
- 9 A. Yildiz, S. B. Lisesivdin, S. Acar, and M. Kasap "Activation Mechanism in InGaN Grown By MOVPE" *AIP Conf. Proc.* **899** 671 (2007).
- **8** A. Yildiz, <u>S. B. Lisesivdin</u>, S. Acar, and M. Kasap "Mole Fraction Dependence Of Mobility In In<sub>x</sub>Ga<sub>1-x</sub>N Alloys" *AIP Conf. Proc.* **899** 670 (2007).

- 7 <u>S. B. Lisesivdin</u> and M. Kasap "Simulation of the Interfacial AlN Layer on Band Structures and Carrier Densities of AlGaN/GaN HEMT Structures" *AIP Conf. Proc.* **899** 622 (2007).
- 6 <u>S. B. Lisesivdin</u>, A. Yildiz, M. Kasap, and E. Ozbay "Strain Calculations from Hall Measurements in Undoped Al<sub>0.25</sub>Ga<sub>0.75</sub>N/GaN HEMT Structures" *AIP Conf. Proc.* **899** 623 (2007).
- 5 S. B. Lisesivdin, S. Acar, M. Kasap "Transport properties of the 2DEG and minority carriers in AlGaN/GaN HEMT Structures grown by MOCVD" XIII. Solid State Matter Physics Ankara Meeting, P-71, p104 (2006).
- 4 S. Acar, S. B. Lisesivdin, M. Kasap "Two dimensional hole gas (2DHG) formation evidence in AlGaN/GaN/AlN HEMTs" XIII. Solid State Matter Physics Ankara Meeting, P-72, p105 (2006).
- 3 S. B. Lisesivdin, S. Acar, M. Kasap and S. Ozcelik "QMSA Analysis and Effects of Extreme Space-Charge Scattering on the Mobility in III-V Systems grown by MBE" *Turkish Physical Society XXIII. International Conference*, p1214 (2005).
- 2 S. B. Lisesivdin, U. Yurdugul, S. Demirezen, S. Acar and M. Kasap "Galvanomagnetic measurements of LEC grown Te-doped InSb" *XI. Solid State Matter Physics Ankara Meeting*, **P-46**, p79 (2004).
- 1 I. Kara, S. B. Lisesivdin, S. Acar and M. Kasap "Temperature dependence of magnetotransport and electrotransport properties of LEC grown S-doped InAs" XI. Solid State Matter Physics Ankara Meeting, P-34, p 67 (2004).

#### **ADVISING**

PhD's

- **3** E. Kutlu, (Ankara University, Institute of Science, Physics Engineering), 2018- present. Second Advisor.
- 2 P. Narin, (Gazi University, Institute of Science, Physics), 2015 present. Advisor.
- 1 G. Atmaca, (Gazi University, Institute of Science, Physics), Investigations of Low-field Transport and Hot-electron Transport in Passivated AlGaN/GaN HEMTs with Si<sub>3</sub>N<sub>4</sub> 2013 2018. Advisor.

MSc's

- **12** K. B. Sönmez, (Gazi University, Institute of Science, Advanced Technologies), RF Magnetron Sputter System and Passive Circuit Element Resistor Production and Characterization 2016 2019. Advisor.
- 11 M. T. Haliloğlu, (Gazi University, Institute of Science, Advanced Technologies), Back Side Via Hole Etching Application of SiC for GaN-based Field Effect Transistors 2016 2019. Advisor.

- 10 O. Omeroglu, (Gazi University, Institute of Science, Physics), Investigation of the Electronic Properties of Zn, Cd and Hg-doped Graphene Sheets with Ab-Initio Methods, 2016 2018. Advisor.
- 9 R. Ibrahem, (Gazi University, Institute of Science, Physics), Investigation of Electronic and Optical Properties of Wurtzite MgZnO with First Principles Calculations, 2016 2018. Advisor.
- 8 M. Ozturk, (Gazi University, Institute of Science, Physics), Electrical Characteristics and Scattering Analysis of Ultrathin Barrier GaN-Based High Electron Mobility Transistors, 2015 2018. Advisor.
- 7 J. M. M. J. Al-Abbas, (Gazi University, Institute of Science, Physics), Simulation and optimation of GaN-based ultrathin barrier high electron mobility transistors, 2014 2016. Advisor.
- **6** E. Kutlu, (Gazi University, Institute of Science, Physics), Investigation of the effects of Cadmium Doping on Electronic and Optical Properties of Graphene Nanoribbons, 2014 2016. Advisor.
- **5** A. F. Kuloglu, (Gazi University, Institute of Science, Physics), Investigation of Electronic Properties of Pa-terminated Graphene Nanoribbons, *2010-2012*. Advisor.
- **4** G. Atmaca, (Gazi University, Institute of Science, Physics), Numerical Investigation of the 2-Dimensional Carriers in AlQN/AlN/GaN-Based (Q=Ga, In) Transistors with Multi-Quantum Well Back-Barriers, *2010-2012*. Advisor.
- **3** K. Elibol, (Gazi University, Institute of Science, Physics), Investigation of Magnetoconductivity and Surface Properties of Exfoliated and Epitaxially Grown Graphene Samples, 2010-2012. Advisor.
- **2** G. Karakoc, (Gazi University, Institute of Science, Physics), Investigating the Electron Transport Properties of AlInN/AlN/(InGaN)/GaN Heterostructures with InGaN Quantum Wells. 2009-2012. Advisor.
- 1 C. Gunes, (Gazi University, Institute of Science, Physics), Electron and magnetotransport investigation of two dimensional electron gas in ultrathin barrier GaN-based heterostructures. 2009-2012. Advisor.

### PERSONAL INFORMATION AND OTHER EXPERIENCE

Birth date: September 12<sup>th</sup>, 1979 Social Status: Married and have a son.

2018-cont. CEO, Biarsis Ltd. Company, <a href="http://www.biarsis.com/">http://www.biarsis.com/</a>, Ankara, Turkey.

2010-2011 Completed the <u>one-year full-time long</u> military service as Assistant Professor

Air Defence Second Lieutenant at Turkish Army Forces, 8. Corps, Air

Defence Battalion which is located at Ercis, Van, Turkey.

-End of CV-

Last update: May 15th, 2020.

Hereby, I am confirming that all information listed on this CV is correct at this date.